

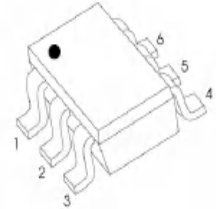
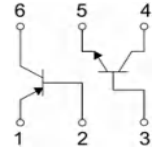


UMZ2N DUAL TRANSISTOR (PNP+NPN)

FEATURES

- Both 2SA1037AK and 2SC2412K chip in a package
- Transistor elements are independent, eliminating interference
- Mounting cost and area be cut in half

Marking: Z2



SOT-363

Absolute maximum ratings (Ta=25°C)

Symbol	Parameter	Limits		Units
		Tr1	Tr2	
V _{CB0}	Collector-Base Voltage	-60	60	V
V _{CEO}	Collector-Emitter Voltage	-50	50	V
V _{EBO}	Emitter-Base Voltage	-6	7	V
I _c	Collector Current	-150	150	mA
P _c	Collector Power Dissipation	150		mW
T _J	Junction Temperature	150		°C
T _{stg}	Storage Temperature	-55-150		°C

ELECTRICAL CHARACTERISTICS (Ta=25°C unless otherwise specified)

Tr1 (PNP)

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Collector-base breakdown voltage	V _{(BR)CBO}	I _C =-50μA, I _E =0	-60			V
Collector-emitter breakdown voltage	V _{(BR)CEO}	I _C =-1mA, I _B =0	-50			V
Emitter-base breakdown voltage	V _{(BR)EBO}	I _E =-50μA, I _C =0	-6			V
Collector cut-off current	I _{CBO}	V _{CB} =-60V, I _E =0			-0.1	μA
Emitter cut-off current	I _{EBO}	V _{EB} =-6V, I _C =0			-0.1	μA
DC current gain	h _{FE}	V _{CE} =-6V, I _C =-1mA	120		560	
Collector-emitter saturation voltage	V _{CE(sat)}	I _C =-50mA, I _B =-5mA			-0.5	V
Transition frequency	f _T	V _{CE} =-12V, I _E =2mA, f=100MHz		140		MHz
Collector output capacitance	C _{ob}	V _{CB} =-12V, I _E =0, f=1MHz			5	pF



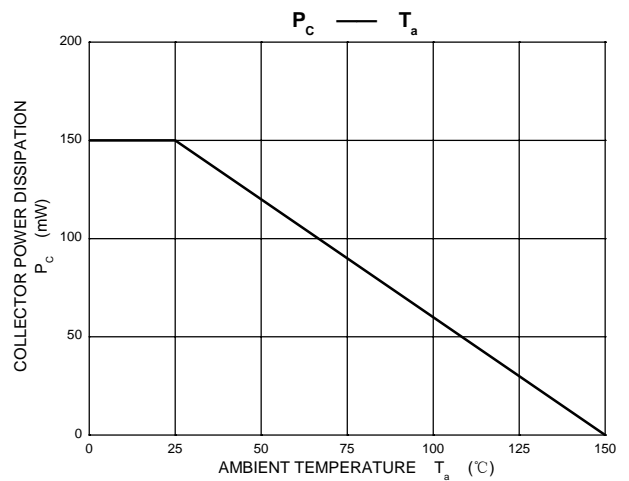
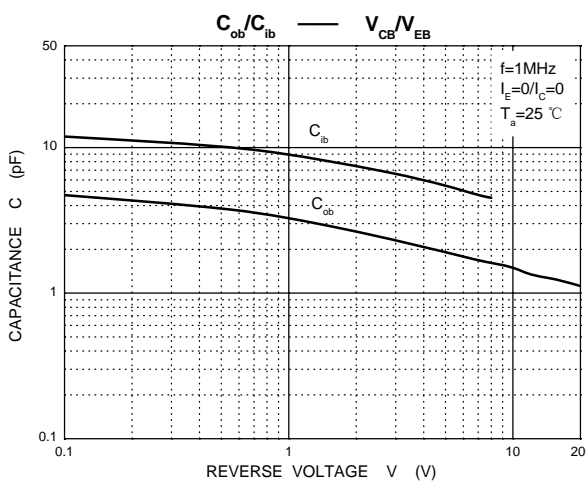
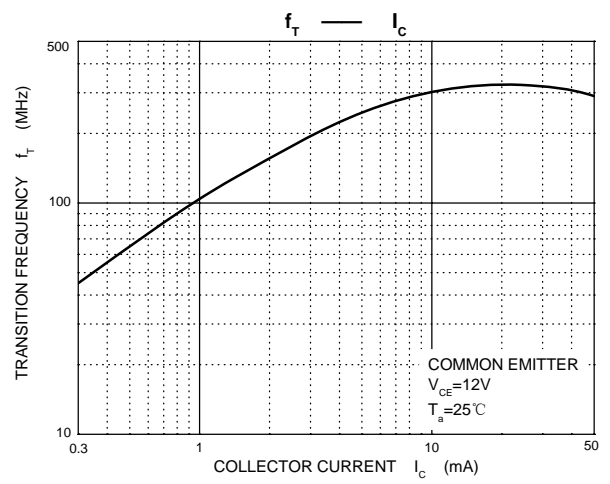
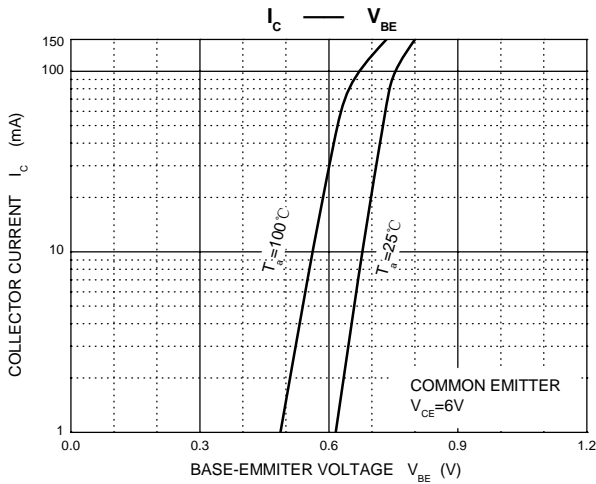
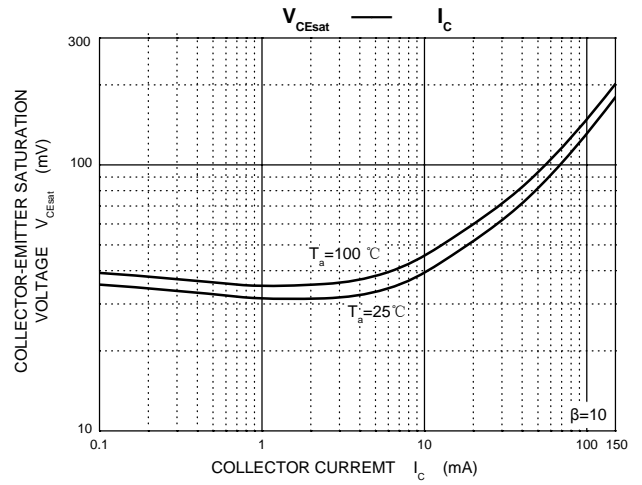
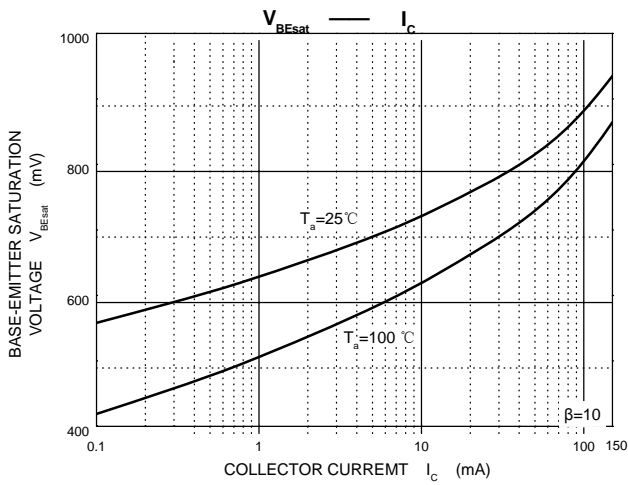
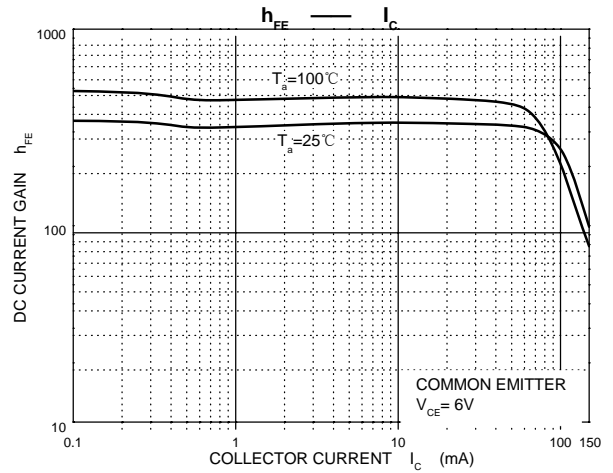
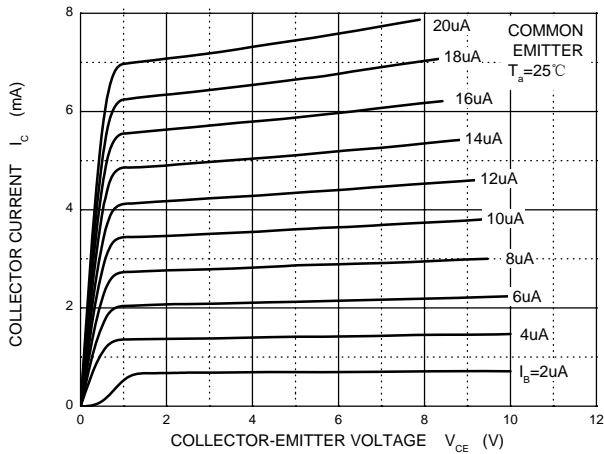
Tr2 (NPN)

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Collector-base breakdown voltage	$V_{(BR)CBO}$	$I_C=50\mu A, I_E=0$	60			V
Collector-emitter breakdown voltage	$V_{(BR)CEO}$	$I_C=1mA, I_B=0$	50			V
Emitter-base breakdown voltage	$V_{(BR)EBO}$	$I_E=50\mu A, I_C=0$	7			V
Collector cut-off current	I_{CBO}	$V_{CB}=60V, I_E=0$			0.1	μA
Emitter cut-off current	I_{EBO}	$V_{EB}=7V, I_C=0$			0.1	μA
DC current gain	h_{FE}	$V_{CE}=6V, I_C=1mA$	120		560	
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C=50mA, I_B=5mA$			0.4	V
Transition frequency	f_T	$V_{CE}=12V, I_E=-2mA, f=100MHz$		180		MHz
Collector output capacitance	C_{ob}	$V_{CB}=12V, I_E=0, f=1MHz$			3.5	pF



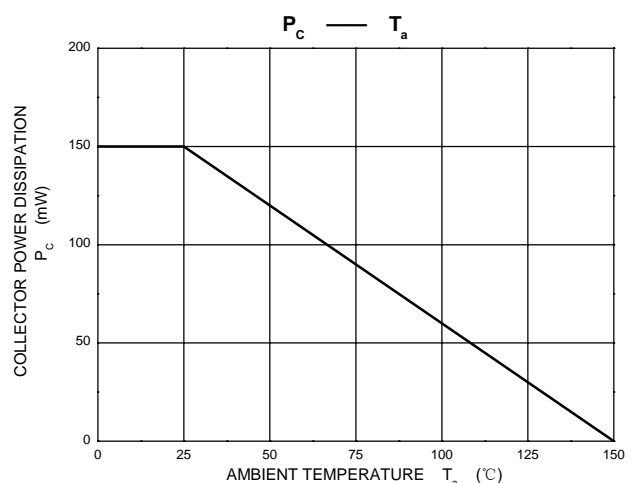
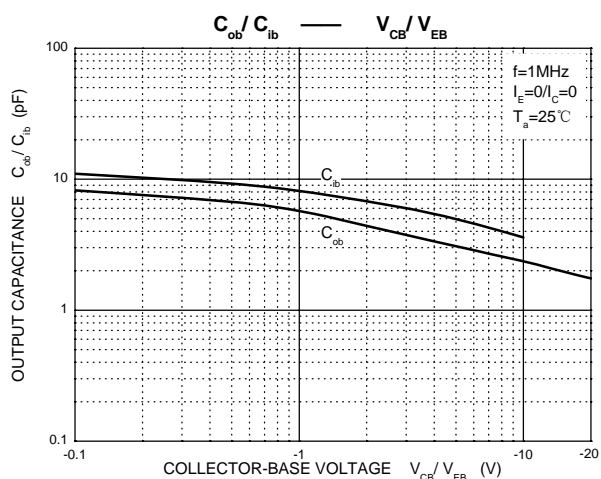
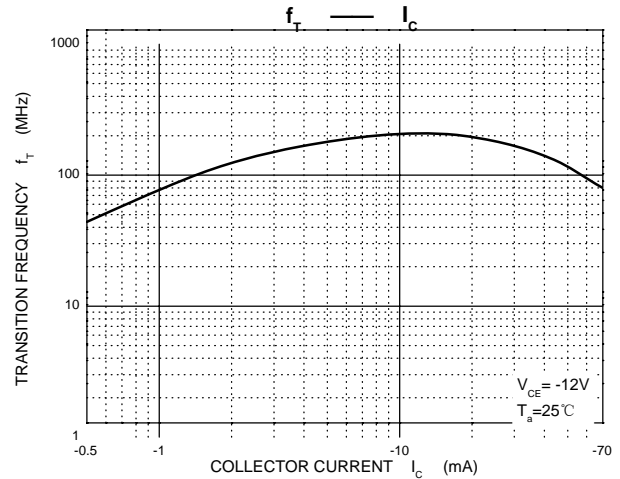
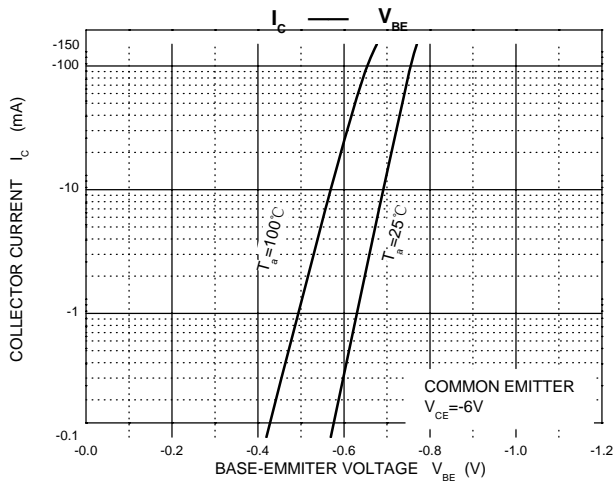
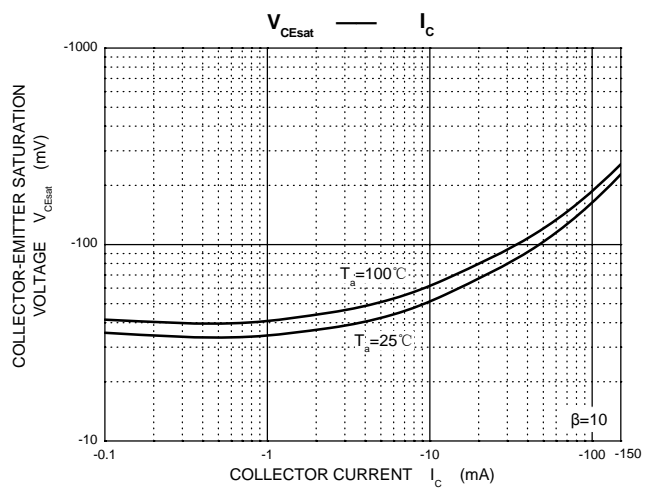
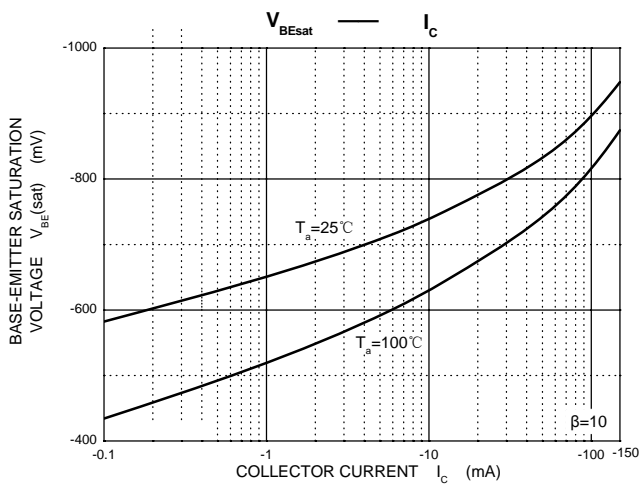
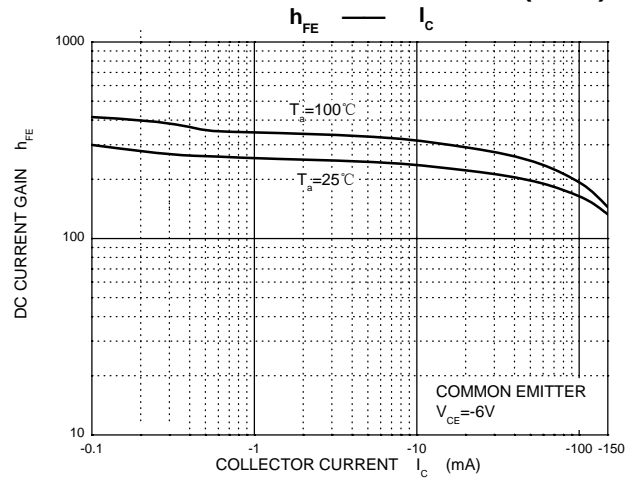
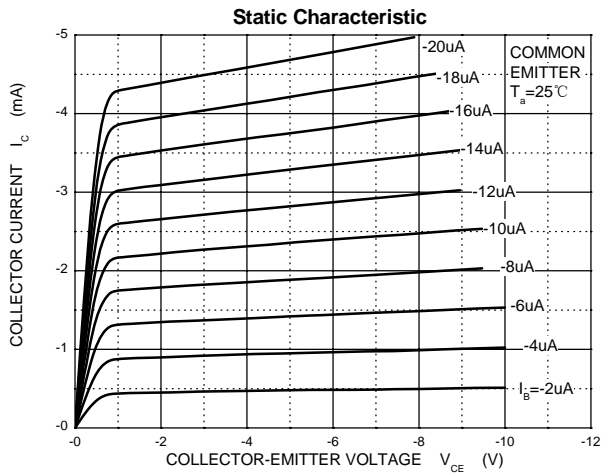
UMZ2N (NPN)

Static Characteristic



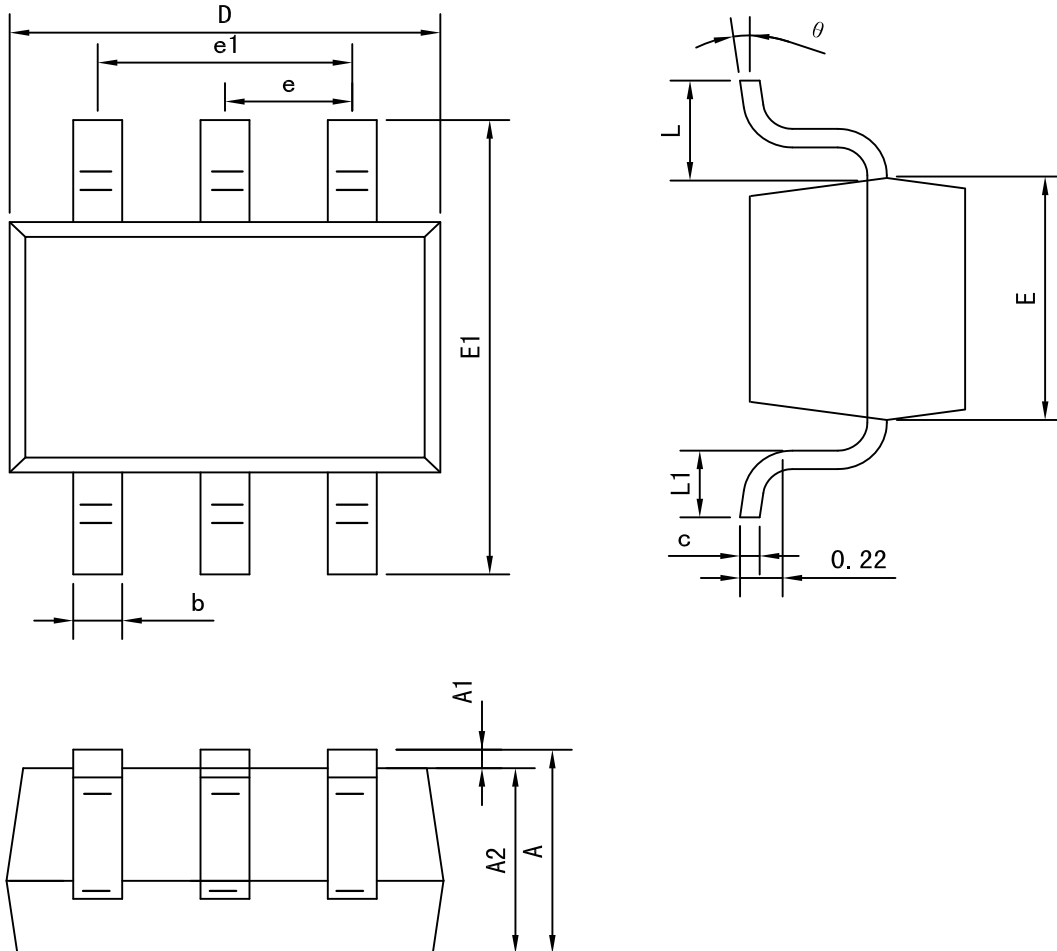


UMZ2N (PNP)





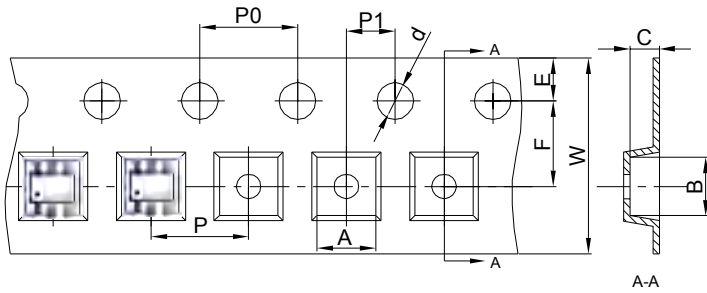
SOT-363 Package outline dimensions



Symbol	Dimension in Millimeters	
	Min	Max
A	0.900	1.100
A1	0.000	0.100
A2	0.900	1.000
b	0.150	0.350
c	0.080	0.150
D	2.000	2.200
E	1.150	1.350
E1	2.150	2.450
e	0.650 TYP	
e1	1.200	1.400
L	0.525 REF	
L1	0.260	0.460
θ	0°	8°



SOT-363 Embossed Carrier Tape



Packaging Description:

SOT-363 parts are shipped in tape. The carrier tape is made from a dissipative (carbon filled) polycarbonate resin. The cover tape is a multilayer film (Heat Activated Adhesive in nature) primarily composed of polyester film, adhesive layer, sealant, and anti-static sprayed agent. These reeled parts in standard option are shipped with 3,000 units per 7" or 17.8cm diameter reel. The reels are clear in color and is made of polystyrene plastic (anti-static coated).

Dimensions are in millimeter										
Pkg type	A	B	C	d	E	F	P0	P	P1	W
SOT-363	2.25	2.55	1.20	Ø1.50	1.75	3.50	4.00	4.00	2.00	8.00

SOT-363 Tape Leader and Trailer

